



الجامعة الإسلامية العالمية ماليزيا  
INTERNATIONAL ISLAMIC UNIVERSITY MALAYSIA  
يُونَيْتِي سَلَامٌ، أَنْتَ رَابِعِيَا مَلِيْسِيَا

**KULLIYAH OF ENGINEERING**

**END OF SEMESTER EXAMINATION  
SEMESTER 2, 2017/2018 SESSION**

Programme	: <b>Engineering</b>	Level of Study	: <b>UG 2</b>
Time	: <b>9:00 am -12:00 pm</b>	Date	: <b>01/06/2018</b>
Duration	: <b>3 Hrs</b>		
Course Code	: <b>EECE 2313/ECE 2133</b>	Section(s)	: <b>1-2</b>
Course Title	: <b>Electronic Circuits</b>		

This Question Paper Consists of **6 (Six)** Printed Pages (Including Cover Page) with **5 (Five)** Questions.

**INSTRUCTION(S) TO CANDIDATES**

**DO NOT OPEN UNTIL YOU ARE ASKED TO DO SO**

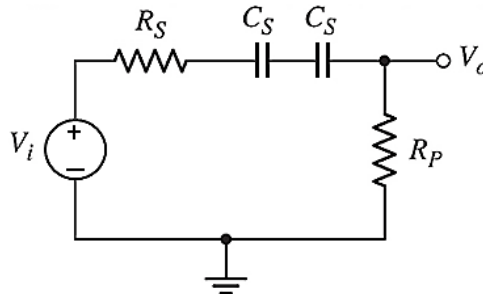
- Total mark of this examination is **100**.
- This examination is worth **50 %** of the total course assessment.
- Answer **ALL QUESTIONS**.
- Only approved calculator with 'KoE approved' sticker is allowed (non-programmable and non-graphical).
- Marks assigned to each problem are listed in the margins.

***Any form of cheating or attempt to cheat is a serious offence which may lead to dismissal.***

***All electronics gadgets are prohibited in the exam hall / venue.  
(e.g. mobile / smart phones, smart watches, and smart glasses)***

**Q.1 [20 marks]**

- (a) Consider the circuit shown in **Fig. 1(a)**, derive the expression (step by step) for the voltage transfer function,  $T(s) = v_o(s)/v_i(s)$ . Find the corner frequency of the circuit if  $R_S = 2 \text{ k}\Omega$ ,  $C_S = 0.5 \text{ }\mu\text{F}$  and  $R_P = 10 \text{ k}\Omega$ . **(8 marks)**

**Fig. 1(a)**

- (b) Draw the Bode plot (magnitude and phase) of the following transfer function. **(8 marks)**

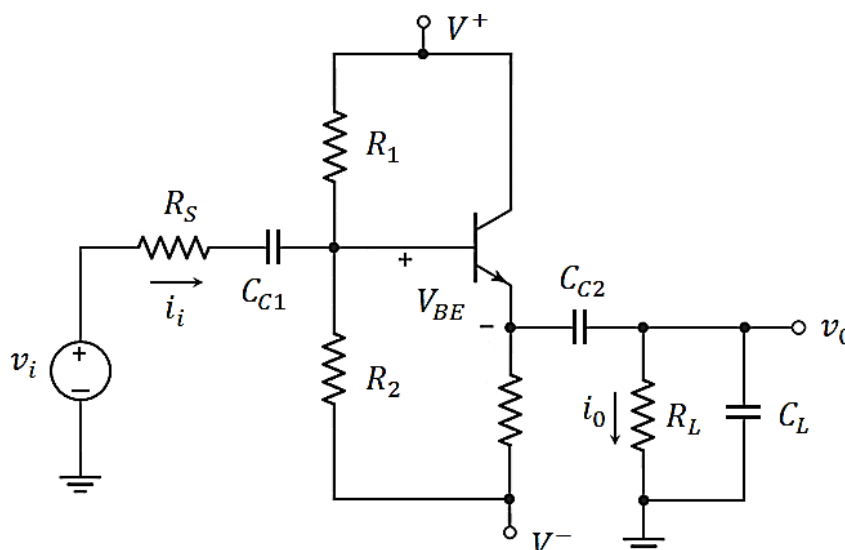
$$T(s) = 10^5 \frac{s(s + 100)}{(s + 50)(s + 1000)}$$

- (c) Determine the magnitude and phase of the transfer function from the plots drawn for **Q1(b)** at frequency  $\omega = 500 \text{ radian/sec}$ . **(4 marks)**

**Q.2 [20 marks]**

- (a) The common emitter amplifier is shown in **Fig. 2(a)** with the following circuit component values,  $R_S = 0.5 \text{ k}\Omega$ ,  $R_1 = 100 \text{ k}\Omega$ ,  $R_2 = 33 \text{ k}\Omega$ ,  $R_E = 1 \text{ k}\Omega$ ,  $R_L = 10 \text{ k}\Omega$ . The BJT has small-signal hybrid- $\pi$  parameters,  $g_m = 40 \text{ mA/V}$ ,  $r_\pi = 3 \text{ k}\Omega$  and  $r_o = \infty$ .

Design the amplifier circuit that operates at lower corner frequency,  $f_L = 20 \text{ Hz}$  and the bandwidth of the amplifier,  $\text{BW} = 25 \text{ kHz}$ . Determine the midband current gain of the designed amplifier in dB. **(14 Marks)**



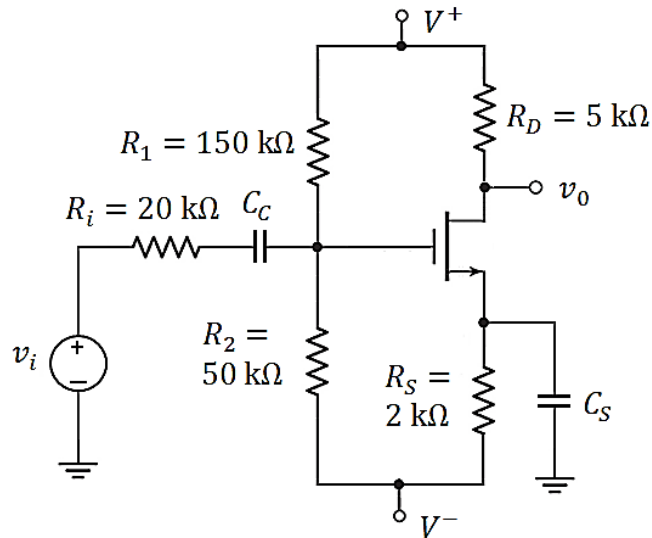
**Fig. 2(a)**

(b) A common source amplifier is shown in **Fig. 2(b)** that operates at very high frequencies.

The coupling and bypass capacitors have very large values. The transistor parameters are:  $g_m = 2 \text{ mA/V}$ ,  $r_o = 100 \text{ k}\Omega$ ,  $C_{gs} = 50 \text{ fF}$  and  $C_{gd} = 8 \text{ fF}$ .

(i) Draw the simplified high-frequency small signal equivalent circuit diagram and Miller equivalent circuit diagram. **(3 marks)**

(ii) Evaluate the upper 3dB frequency,  $f_H$  with and without considering Miller capacitance. **(3 marks)**



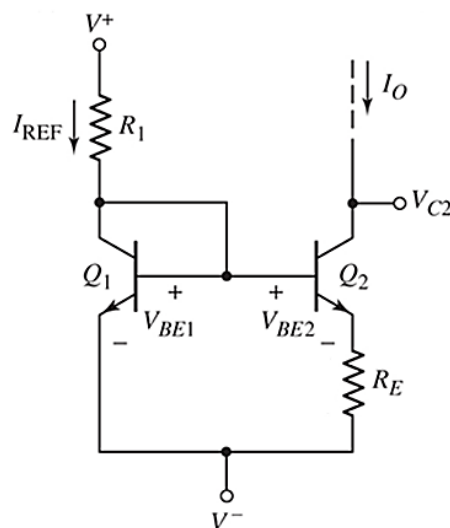
**Fig. 2(b)**

**Q.3 [20 marks]**

(a) The circuit diagram of a Wildar current source is shown in **Fig. 3(a)**. Design the circuit such that  $I_{REF} = 0.5 \text{ mA}$  and  $I_O = 50 \mu\text{A}$  neglecting the base currents. Also determine  $V_{BE2}$ .

[Given that  $V^+ = 5 \text{ V}$ ,  $V^- = -5 \text{ V}$  and  $V_A = \infty$ ]

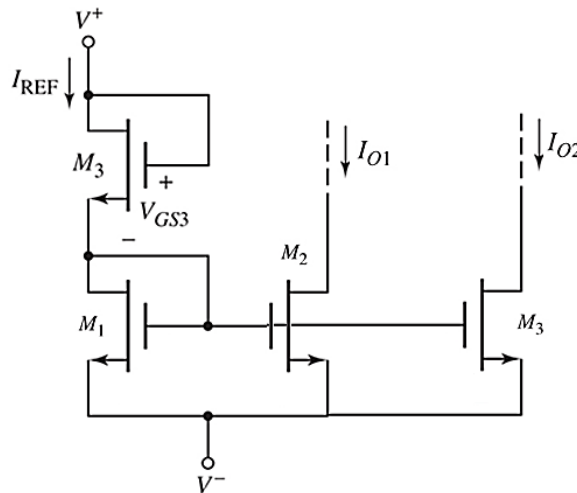
**(10 marks)**



**Fig. 3(a)**

(b) Draw the small signal equivalent circuit diagram of the current source shown in **Fig. 3(a)**. **(2 marks)**

(c) Design a MOSFET current source as shown in **Fig. 3(c)** such that  $I_{REF} = 0.5\text{mA}$ ,  $I_{O1} = 1\text{mA}$ ,  $I_{O2} = 20\text{mA}$  and  $V_{Dsat3} = 0.6\text{V}$ . The bias voltage  $V^+ = +5\text{V}$  and  $V^- = -5\text{V}$ . The transistors are available with parameters  $k'_n = 40\ \mu\text{A}/\text{V}^2$ ,  $V_{TN} = 1\text{V}$  and  $\lambda = 0$ . **(8 marks)**

**Fig. 3(c)****Q.4 [20 marks]**

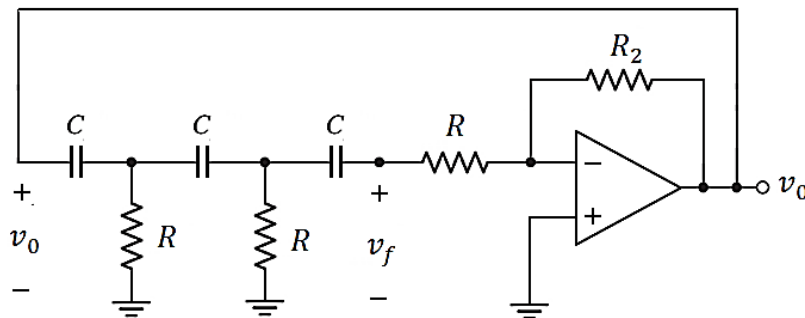
(a) Draw a basic configuration of a feedback amplifier and show in step by step that the bandwidth of the amplifier is increased by a factor of  $(1 + \beta A)$ . **(5 marks)**

(b) Draw the block diagram and small signal equivalent circuit diagram of a Series-Series ideal feedback amplifier. Analyze step by step the feedback amplifier to find the expression of the closed loop gain,  $A_f$ , the input resistance,  $R_{if}$  and the output resistance,  $R_{of}$  in terms of open-loop amplifier gain,  $A$  and feedback amplifier gain,  $\beta$ . **(10 marks)**

(c) For a shunt series feedback system, the open-loop gain  $A_i$  and closed loop gain  $A_{if}$  of the amplifier are  $10^5$  and 60 respectively. Find the input resistance and output resistance of the amplifier if the input and output resistances of the basic amplifier are  $R_i = 15\text{ k}\Omega$  and  $R_o = 35\text{ k}\Omega$  respectively. Also find the closed loop bandwidth if the open loop amplifier bandwidth is 1 kHz. **(5 marks)**

**Q.5 [20 marks]**

- (a) A phase-shift RC oscillator is shown in **Fig. 5(a)**. Derive the transfer function of the feedback network,  $\beta(s) = \frac{v_f(s)}{v_o(s)}$  by neglecting the loading effect of the C-R stage. Derive the frequency of oscillation,  $f_o$ . Also find the minimum amplifier gain for sustained oscillations. **(16 Marks)**

**Fig. 5(a)**

- (b) Design the phase shift oscillator as shown in **Fig. 5(a)** which oscillation frequency is  $f_o = 10$  kHz. **(4 Marks)**

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**USEFUL FORMULA**


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<b>BJT</b>	<b>MOSFET</b>
$i_C = I_S e^{v_{BE}/V_T} \cdot \left(1 + \frac{v_{CE}}{V_A}\right)$ $g_m = \frac{I_{CQ}}{V_T}$ $r_\pi = \frac{\beta V_T}{I_{CQ}}$ $r_o = \frac{V_A}{I_{CQ}}$ $V_T = 26 \text{ mV}$ $V_{BE(on)} = 0.7 \text{ V}$	$I_D = \frac{1}{2} k_n' \left(\frac{W}{L}\right) (V_{GS} - V_T)^2 (1 + \lambda V_{DS})$ $g_m = 2\sqrt{K_n I_{DQ}}$ $r_o = \frac{1}{\lambda I_{DQ}}$

**END OF PAPER**